

BCR30CM-8LB

400V-30A-Triac

Medium Power Use

R07DS1105EJ0100 Rev.1.00 Aug 08, 2013

Features

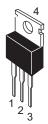
- $I_{T (RMS)} : 30 A$ V_{DRM} : 400 V
- $I_{FGT I}$, $I_{RGT I}$, $I_{RGT III}$: 30 mA

- Tj: 150 °C
- Planar Passivation Type
- Non-Insulated Type

Outline

RENESAS Package code: PRSS0004AG-A

(Package name: TO-220AB)





- T₁ Terminal
 T₂ Terminal
 Gate Terminal

- 4. T₂ Terminal

Applications

Vacuum cleaner, electric heater, light dimmer, copying machine, and other general controlling devices

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Farameter	Syllibol	8		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	400	V	
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	500	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T(RMS)}	30	A	Commercial frequency, sine full wave 360° conduction, Tc = 107°C ^{Note3}
Surge on-state current	I _{TSM}	300	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	450	A ² s	Value corresponding to 1 cycle of half
				wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	2.1	g	Typical value

Electrical Characteristics

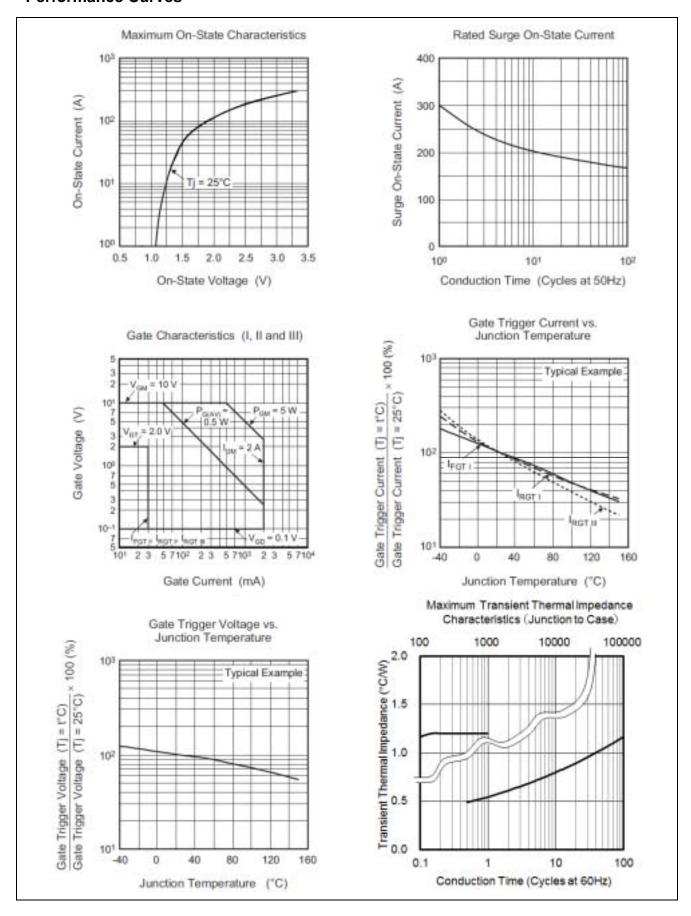
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I_{DRM}	_	_	3.0	mA	Tj = 125°C, V _{DRM} applied
			_	_	5.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V_{TM}	_	_	1.5	V	$Tc = 25^{\circ}C, I_{TM} = 45 A,$
							Instantaneous measurement
Gate trigger voltage ^{Note2}	I	$V_{FGT\ I}$		_	2.0	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω ,
	II	V_{RGTI}		_	2.0	V	$R_G = 330 \Omega$
	III	V_{RGTIII}	_	_	2.0	V	
Gate trigger current ^{Note2}	I	I _{FGT I}		_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω ,
	II	$I_{RGT\;I}$		_	30	mA	$R_G = 330 \Omega$
	III	I _{RGT III}	_	_	30	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$
			0.1	_	_	V/μs	$Tj = 150$ °C, $V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th(j-c)}	_	_	1.1	°C/W	Junction to case ^{Note3 Note4}
Critical-rate of rise of off-stat	te	(dv/dt)c	10	_	_	V/μs	Tj = 125°C
commutating voltage ^{Note5}			1	_	_	V/μs	Tj = 150°C

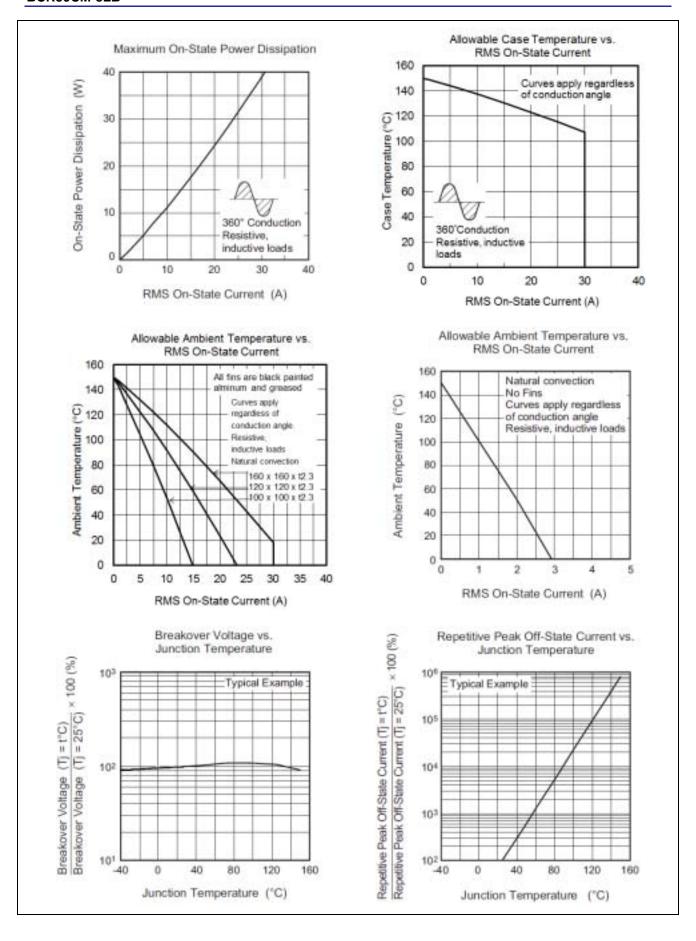
Notes: 1. Gate open.

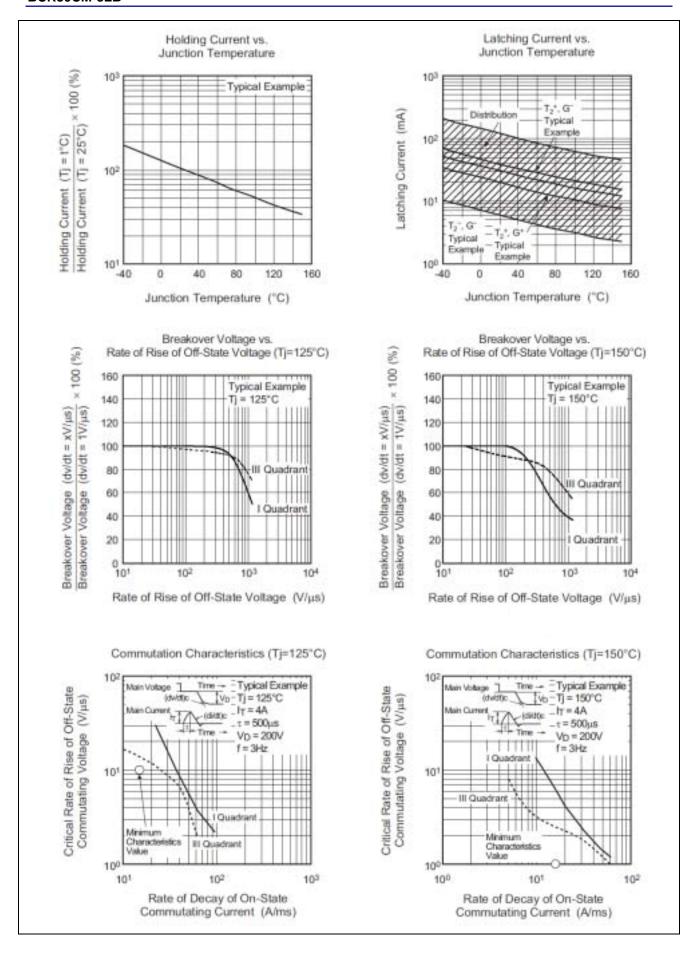
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Case temperature is measured at the T_2 tab 1.5 mm apart from the molded case.
- 4. The contact thermal resistance $R_{th\;(c\text{-}f)}$ in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

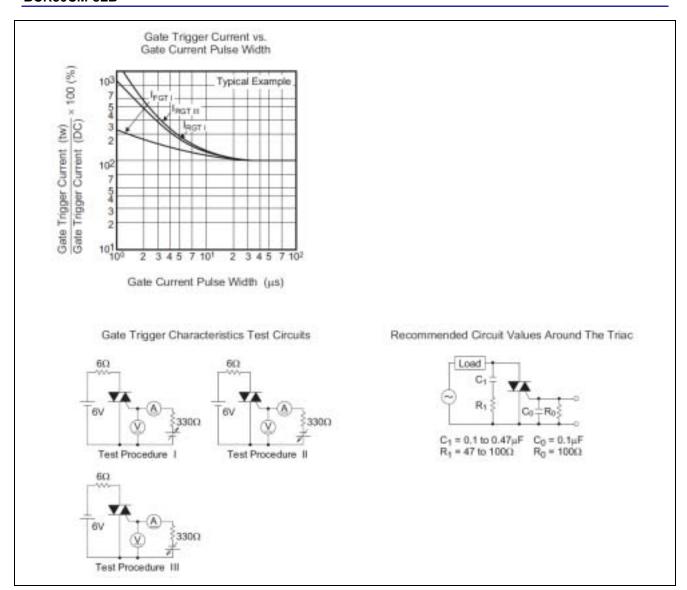
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125/150°C	Supply Voltage
 2. Peak off-state voltage V_D = 400 V 3. Rate of decay of on-state commutating current (di/dt)c = -16 A/ms 	Main Current Main Voltage (di/dt)c Time (dv/dt)c

Performance Curves

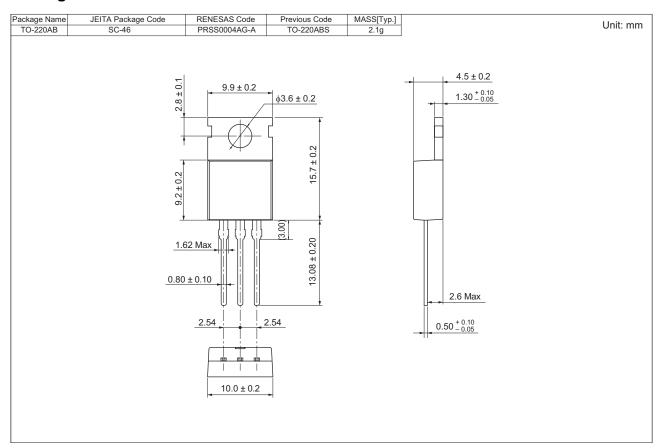








Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR30CM-8LB#BB0	Tube	50 pcs.	Straight type
BCR30CM-8LB-A8#BB0	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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